ELECTRICAL PACKAGE DESIGN

Major design tasks & Functions

Design Tasks

- > Creating a signal distribution system
- > Creating a power/grounding system
- ➤ Overcoming parasitic reactance's an obstacle

Functions

- ➤ Provide signal/power distribution
- Protection from environment(chemical/physical)

Thermal mitigation

- Connectivity within package, between layers
- > Potential for lumped passive elements

Fundamentals of Electrical Design

- Ohm's Law
- Skin Effect
- Kirchhoff's Laws (KVL/KCL)
- Noise
- Time Delay
- Simultaneous Switching Noise (ssn)
- Transmission Lines
- Crosstalk
- EMI

Electrical Anatomy of Packaging

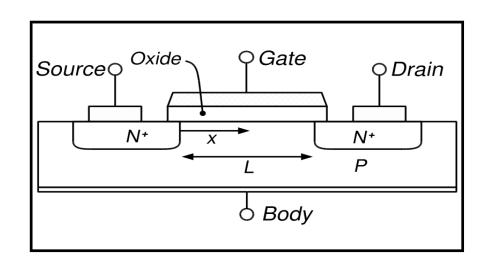
- Dealing with parasitic elements
 Cause delay, skew, lead/lag, and transient power fluctuations
 Transmitted signal winds up being degraded
- Primary challenge:
 - Handling non-ideal effects
 - Package design must meet specifications

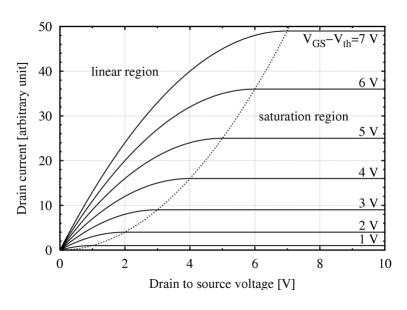
Devices and Interconnections

MOSFETs are most frequent devices

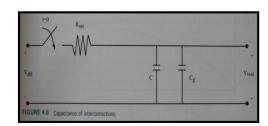
Operated as a switch (cutoff / saturation modes)

Binary state at the gate determines mode





- Non-idealities in MOSFETs
 - On-resistance R_{ON}
 - Leads to non-zero voltage drop
 - Thermal losses
 - Potential for other parasitic problems and delays
 Switching delay, rise/fall times
 - Limit speed of packaged circuit
 - Consume energy to charge/discharge gate capacitance Capacitive Delay of Interconnections



- Kirchhoff's Laws and Transit Time Delay
 - Propagation at C (3 x 10⁸ m/s) in air
 - Propagation at <C in solids
 - KVL/KCL fail to account for delays or phase shift
 - Time domain analysis
 - Time of Flight
 - Frequency domain analysis
 - Main parameter is wavelength
 - $\lambda = c/f$
 - speed in material = $(3 \times 10^8)/(\varepsilon_r \mu_r)^{1/2}$ [m/s]

- Transmission Line Behavior of Interconnections $L\Delta z$ is total series inductance of equivalent circuit $R\Delta z$ is total series resistance of equivalent circuit
- Waves Between Digital Gates
 Parallel strip is common, easy to design
 Microstrip, embedded microstrip, and stripline
 - Microstrip: between air and dielectric
 - E-Microstrip: embedded within a dielectric
 - Stripline: connection between two metal layers

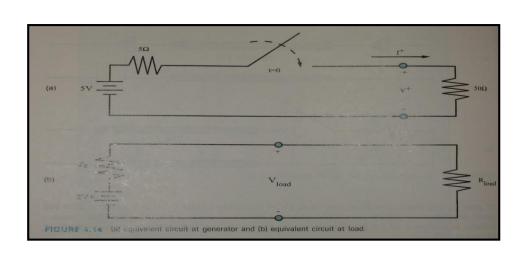
Signals exhibit a finite velocity

Output from line is not instantaneous

$$v_p = 1/(LC)^{1/2}$$

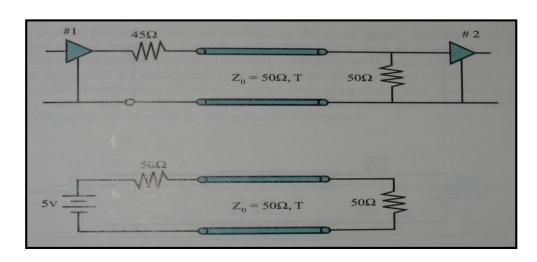
Input appears to be a resistance (top figure)

Load terminated by MOSFET (high resistance)



Equivalent circuit at (a) generator and (b) load

Match the Terminations and Line Impedances
 Basic Electromagnetics
 Unmatched terminations lead to reflections
 How to match previous figure:



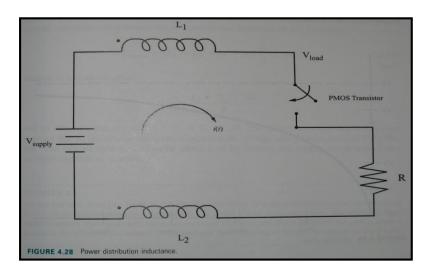
(a) Matching by adding 45 ohm series resistance, and (b) Resulting system with matched impedances.

- Interconnects must also carry power
 - Active elements require power to operation
 - Voltage drop and inductive effects are main issues
 - Supply voltage may not be the same everywhere due to V=IR drops throughout the package

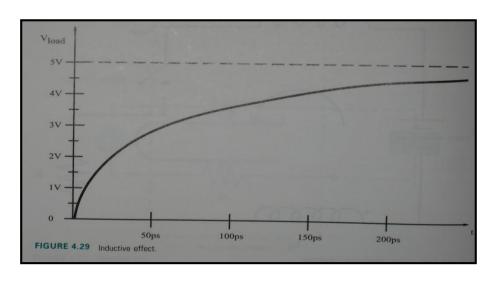
Parasitic inductance leads to voltage drops:

- $V_{\text{supply}} = (L_1 + L_2)(di/dt) + R*i(t)$
- $V_{load}(t) = V_{supply}(1-e^{-t/T})u(t)$
- The load voltage is therefore the supply voltage plus the induced time constant parameter

 Effective power distribution inductances
 Inductances L1 and L2 are for voltage and ground leads for the package



Power distribution inductance



Inductive effect

• Effective Inductance

Used to evaluate the power distribution performance of the package

Contribution can be either additive or subtractive

- Additive: currents are in same direction
- Subtractive: currents are in opposite directions
- Assuming a mutual inductance *M* between inductors:

$$V_{\text{supply}} = (L_1 + L_2 - 2M)(di/dt) + Ri(t)$$

Time Constant:
$$T = (L_1 + L_2 - 2M)/R$$

Effective Inductance:
$$L_{eff} = L_1 + L_2 + M$$

(reduced due to mutual inductance between voltage and ground leads of the package)

Power Supply Noise

Local, real supplies source finite current

With series inductances, the local Vdd will drop since the inductor current cannot change instantaneously

- Result: transient fluctuations in supply voltage
- $\Delta V = L_{eff}(dI/dt)$
- Called *simultaneous switching noise* (ssn)
- Effect of Packaging on Inductance

Minimizing inductance reduces supply noise

Effective inductance varies from package to package (quad flat pack, QFP, or ball grid arrays, BGAs, etc.)

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